Single-Channel Ultra-Fast Gate Driver **For Automotive**

BD2311ANVX-C

General Description

BD2311ANVX-C is a single gate driver capable of driving GaN HEMTs at Ultra-Fast with narrow pulses, which can contribute to the long-range and high accuracy of LiDAR. It can supply 5.4 A output current in a small 6-pin SON package. As a protection function, the driver includes an Undervoltage Lockout (UVLO) between VCC and GND.

Features

- AEC-Q100 Qualified^(Note 1)
- Gate Driver Voltage Range 4.5 V to 5.5 V
- Minimum Input Pulse Width 1.25 ns (220 pF load)
- Typical Rise Time 0.65 ns (220 pF load)
- Typical Fall Time 0.70 ns (220 pF load)
- Built-in Undervoltage Lockout (UVLO) between VCC
- Inverting and Non-inverting Inputs
- Small Package SSON06RX2020 (Note 1) Grade 1

Key Specifications

Gate Driver Voltage Range: 4.5 V to 5.5 V Output Current I_{OH} / I_{OL}: 5.4 A / 2.7 A (Typ)

Turn-on / Turn-off Delay Time: 3.4 ns / 3.0 ns (Typ)

Operating Temperature Range: -40 °C to +125 °C

Package SSON06RX2020

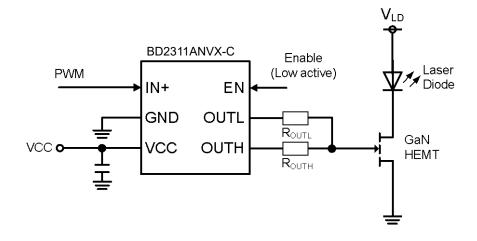
W (Typ) x D (Typ) x H (Max) 2.0 mm x 2.0 mm x 0.6 mm



Applications

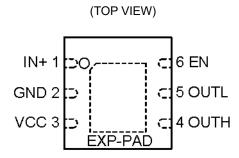
- Automotive Equipment
- Automotive LiDAR
- DC / DC Converters
- Augmented Reality

Typical Application Circuit



Target Spec

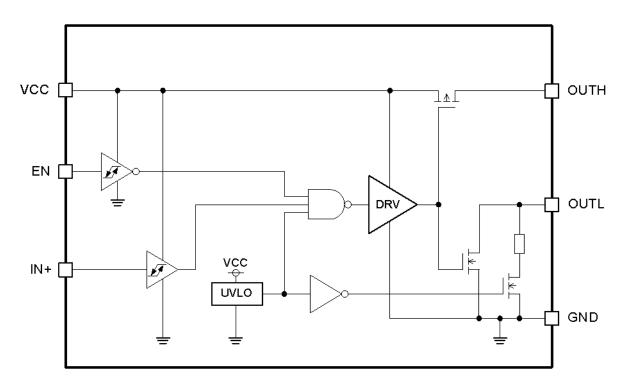
Pin Configuration



Pin Descriptions

Pin No.	Pin Name	Function
1	IN+	Logic input pin.
2	GND	Ground.
3	VCC	Power supply.
4	OUTH	Pull-up gate drive output.
5	OUTL	Pull-down gate drive output.
6	EN	Enable pin. (Low active)
-	EXP-PAD	Connect EXP-PAD to the internal PCB ground plane. Exposed pad for thermal cooling and internal not connected to GND.

Block Diagram



Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Rating	Unit
Supply Voltage	VCC	-0.3 to +6.5	V
Input Voltage (IN+)	V _{IN+}	-5.0 to +7.0	V
Input Voltage (EN)	V_{EN}	-5.0 to +7.0	V
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

Thermal Resistance (Note 1)

Developed	Curah al	Thermal Resistance (Typ)		1.1:4	
Parameter	Symbol	1s ^(Note 3)	2s2p ^(Note 4)	Unit	
SSON06RX2020					
Junction to Ambient	θ_{JA}	284.5	83.2	°C/W	
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	35.0	22.0	°C/W	

(Note 1) Based on JESD51-2A (Still-Air).

(Note 2) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

(Note 3) Using a PCB board based on JESD51-3. (Note 4) Using a PCB board based on JESD51-5, 7

Note 4) Using a FCB board based of	JL3D31-3, 7.				
Layer Number of Measurement Board	Material	Board Size			
Single	FR-4	114.3 mm x 76.2 mm x	k 1.57 mmt		
Тор					
Copper Pattern	Thickness				
Footprints and Traces	70 µm				
Layer Number of	Material	Board Size Thermal Via ⁽¹⁾		Thermal Via ^{(No}	te 5)
Measurement Board	Material	Board Oize		Pitch I	Diameter
4 Layers	FR-4	114.3 mm x 76.2 mm	x 1.6 mmt	1.20 mm 4	0.30 mm
Тор		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70 µm	74.2 mm x 74.2 mm	35 µm	74.2 mm x 74.2 mm	70 µm

(Note 5) This thermal via connect with the copper pattern of layers 1,2, and 4. The placement and dimensions obey a land pattern.

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Supply Voltage	VCC	4.5	5.0	5.5	V
Input Voltage (IN+)	V _{IN+}	-0.3	-	VCC	V
Input Voltage (EN)	VEN	-0.3	-	VCC	V
Operating Temperature	Topr	-40	+25	+125	°C

Electrical Characteristics (Unless otherwise specified VCC = 5 V, Tj = -40 °C to +125 °C)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Circuit Current			1		II.	
VCC Operating Current	Icc	-	38.7	46.0	mA	30 MHz (50 % duty), 2 Ω as R _{OUTH} and R _{OUTL} , 100 pF load
VCC Shutdown Current	Iccshd	-	0.61	1.00	mA	$V_{IN+} = V_{EN} = 0 V$
Undervoltage Lockout (UVLO)						
UVLO Detect Threshold Voltage	V _{UVDOWN}	2.9	3.6	4.3	V	VCC falling
UVLO Reset Threshold Voltage	Vuvup	3.1	3.9	4.5	V	VCC rising
UVLO Hysteresis Voltage	V _{UV_HYS}	-	0.3	-	V	
Input						
IN+, EN Pin High Threshold Voltage	ViH	1.7	2.1	-	V	
IN+, EN Pin Low Threshold Voltage	VIL	-	1.3	1.8	V	
Hysteresis Voltage	V _{HYS}	-	8.0	1.0	V	
Output	<u>, </u>					
Peak Source Current ^(Note 1)	Іон	-	5.4	-	Α	
Peak Sink Current ^(Note 1)	loL	-	2.7	-	Α	
Turn-on Propagation Delay Time	ton	-	3.4	6.0	ns	100 pF load
Turn-off Propagation Delay Time	toff	-	3.0	7.5	ns	100 pF load
Output Rise Time	t _R	-	0.65	-	ns	0 Ω series 220 pF load
Output Fall Time	t⊧	-	0.70	-	ns	0 Ω series 220 pF load
Minimum Input Pulse Width	t _{INMIN}	-	1.25	-	ns	0 Ω series 220 pF load

(Note 1) Not Tested

Typical Performance Curves

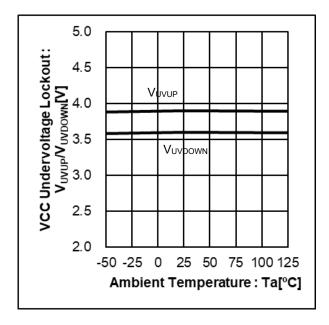


Figure 1. VCC Undervoltage Lockout vs Ambient Temperature (VCC = 5 V, 2 Ω as Routh and Routl, 100 pF load)

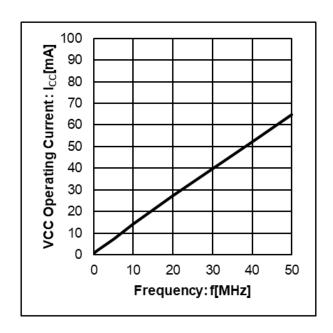


Figure 2. VCC Operating Current vs Frequency (VCC = 5 V, 2 Ω as R_{OUTH} and R_{OUTL}, 100 pF load)

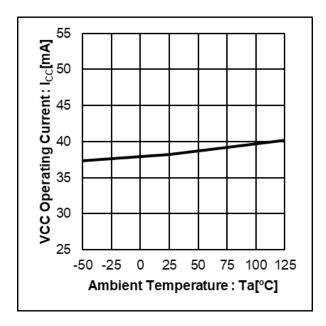


Figure 3. VCC Operating Current vs Ambient Temperature (VCC = 5 V, 2 Ω as Routh and Routl, 100 pF load)

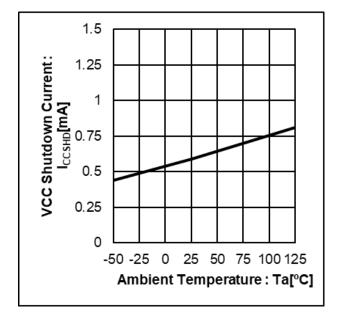


Figure 4. VCC Shutdown Current vs Ambient Temperature (VCC = 5 V, V_{IN+} = V_{EN} = 0 V)

Typical Performance Curves - continued

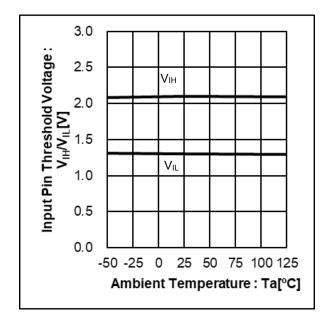


Figure 5. Input Pin Threshold Voltage vs Ambient Temperature

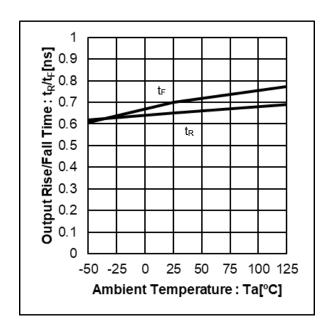


Figure 6. Output Rise/Fall Time vs Ambient Temperature (VCC = 5 V, 0 Ω as Routh and Routl, 220 pF load)

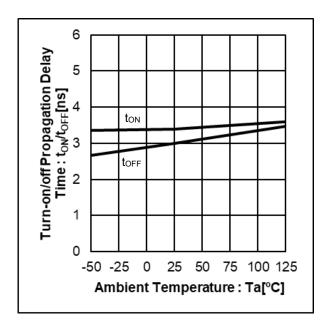


Figure 7. Turn-on/off Propagation Delay Time vs Ambient Temperature (VCC = 5 V, 0 Ω as R_{OUTH} and R_{OUTL}, 100 pF load)

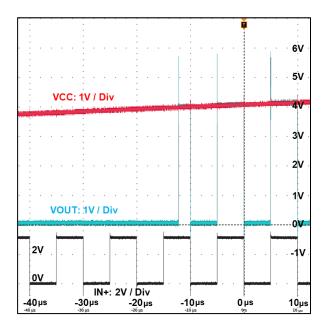


Figure 8. Startup Time (0 Ω as Routh and Routl, 220 pF load)

Typical Performance Curves - continued

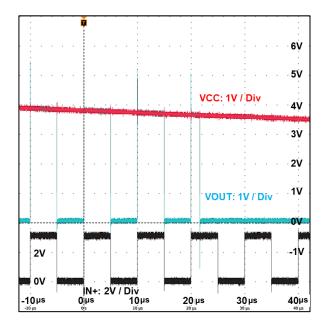


Figure 9. Shutdown Time (0 Ω as Routh and Routl, 220 pF load)

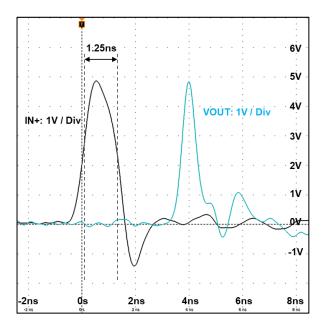


Figure 10. Minimum Input Pulse Width (VCC = 5 V, 0 Ω as Routh and Routl, GNE1040TB^(Note 1)) (Note 1) Caution, GNE1040TB can't be applied for Automotive

Timing Chart

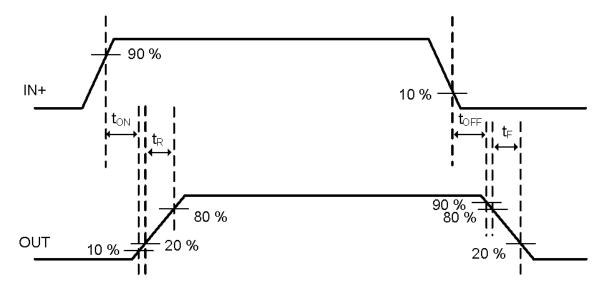


Figure 11. Timing Chart

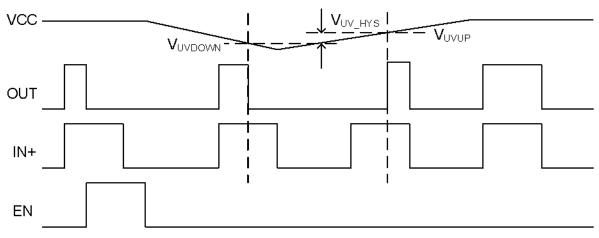


Figure 12. UVLO Timing Chart

Function Table

Table 1. The device will operate in following mode when in UVLO state.

IN+	EN	OUTH	OUTL
X ^(Note 6)	X ^(Note 6)	OPEN	L

⁽Note 6) X is not dependent on the value.

Table 2. The device will operate in following mode when not in UVLO state.

IN+	EN	OUTH	OUTL
L	L	OPEN	L
Н	L	Н	OPEN
L	Н	OPEN	L
Н	Н	OPEN	L

Application Components Selection Method

(1) Gate Resistor

The gate resistor $R_{G(ON/OFF)}$ is selected to the switching speed of the power device. The switching time (tsw) is defined as the time spent to reach the end of the plateau voltage, so the turn-on gate resistor $R_{G(ON)}$ can be calculated using the following formulas.

$$I_G = \frac{Q_{gs} + Q_{gd}}{t_{SW}} \tag{1}$$

$$R_{TOTAL(ON)} = R_{PON} + R_{G(ON)} = \frac{VCC - V_{GS(TH)}}{I_G} \quad [2]$$

$$t_{SW} = \frac{Q_{gs} + Q_{gd}}{I_G} = \frac{(Q_{gs} + Q_{gd})(R_{PON} + R_{G(ON)})}{(VCC - V_{GS(TH)})}$$
[3]

Where:

 I_G is the gate current of the power device.

 $Q_{as}\,$ is the charge between gate and source of the power device.

 Q_{ad} is the charge between gate and drain of the power device.

 $V_{GS(TH)}$ is the threshold voltage of the power device.

The turn-on gate resistance can be changed to control output slew rate (dV_D/dt). The slew rate of the power device is determined by the following equation.

$$\frac{dV_D}{dt} = \frac{I_G}{C_{rss}} \tag{4}$$

where:

 \mathcal{C}_{rss} is the feedback capacitance.

The gate resistance is determined as follows by substituting equation [4] into equation [2].

$$R_{TOTAL(ON)} = R_{PON} + R_{G(ON)} = \frac{VCC - V_{GS(TH)}}{c_{rss} \times \frac{dV_D}{dt}}$$
 [5]

$$R_{G(ON)} = \frac{VCC - V_{GS(TH)}}{C_{rss} \times \frac{dV_D}{dt}} - R_{PON}$$
 [6]

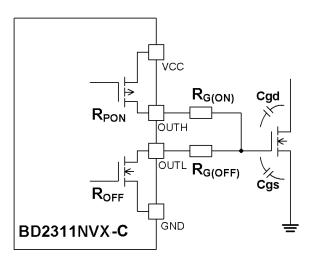


Figure 13. Gate Driver Equivalent Circuit

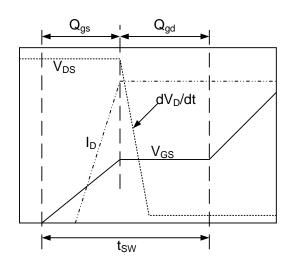


Figure 14. Gate Charge Transfer Characteristics

When other power devices are turned on, current flows in the power device which is off through Cgd. At this point, the gate resistance ($R_{G(OFF)}$) should be set so that the gate voltage does not exceed the threshold of the power device and turn on the power device itself.

$$V_{GS(TH)} \ge \left(R_{NOFF} + R_{G(OFF)}\right) \times I_G = \left(R_{NOFF} + R_{G(OFF)}\right) \times C_{gd} \times \frac{dV_D}{dt}$$
[7]

$$R_{G(OFF)} \le \frac{V_{GS(TH)}}{C_{gd} \times \frac{dV_D}{dt}} - R_{NOFF}$$
 [8]

Application Components Selection Method – continued

(2) Input Capacitor

A low-ESR ceramic capacitor should be used near the VCC pin to reduce input ripple voltage. In considering of the DC bias characteristic, it is recommended $0.5~\mu F$ or more between VCC and GND.

PCB Layout

The voltage of VCC pin may be risen by the parasitic inductance of the PCB and the bonding wire in the IC.

The mechanism by which VCC voltage rises is Figure 15.

- (1) When the signal with short pulse width is input as an input signal, it is turned off in the state that Pch-FET of the final stage is turned on and flows current.
- (2) When Pch-FET is turned off while current is flowing, VCC voltage is risen by the parasitic inductance.

When VCC voltage is risen and over absolute maximum ratings, it can damage the IC.

To reduce the rising of VCC voltage, please locate a ceramic capacitor which is low-ESR near the VCC pin and the GND pin, and connect it so that parasitic inductance L_{VCC} and L_{GND} in the PCB becomes small. It is recommended 1 nH or less each L_{VCC} and L_{GND} .

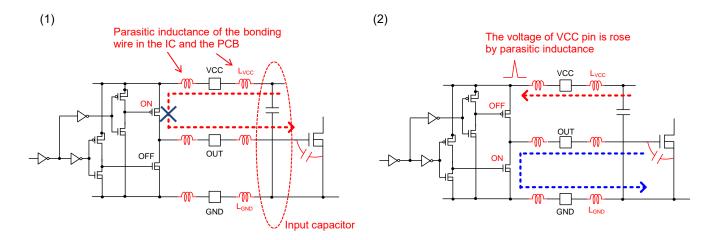
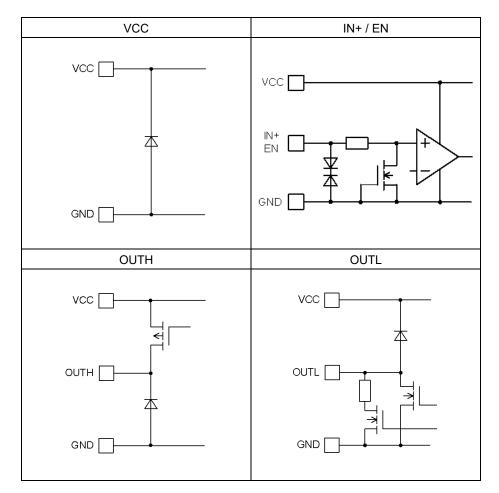


Figure 15. Mechanism of Overshoot

I/O Equivalence Circuits



Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

Operational Notes - continued

8. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

9. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

10. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

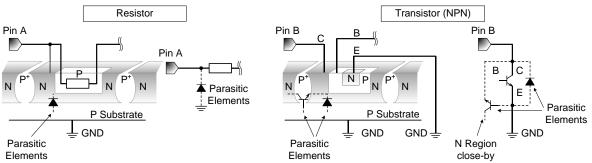
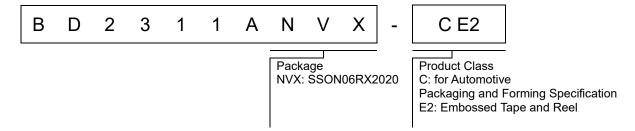


Figure 16. Example of Monolithic IC Structure

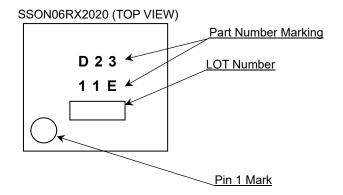
11. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

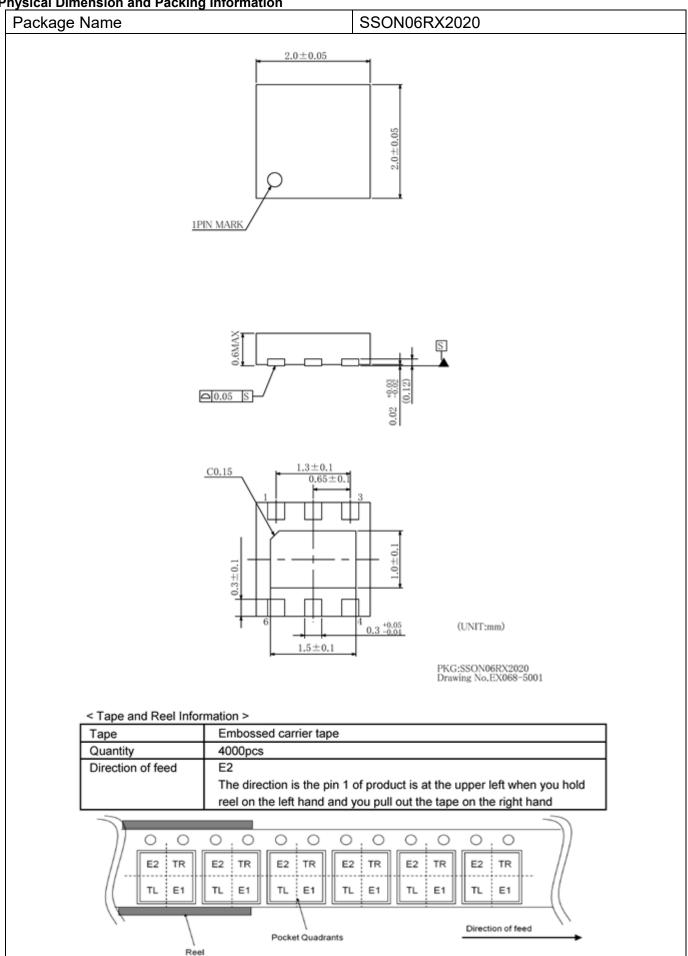
Ordering Information



Marking Diagram



Physical Dimension and Packing Information



Revision History

Date	Revision	Changes
23.Dec.2024	001	New Release

Notice

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(Note1) Medical Equipment Classification of the Specific Applications

ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CL ACCIII	CLASS II b	СГУССШ
ſ	CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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